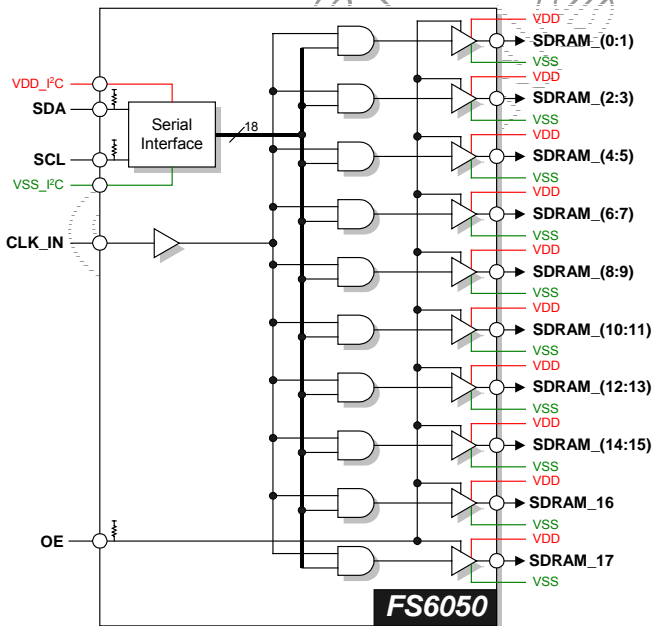


1.0 Features

- Generates up to eighteen low-skew, non-inverting clocks from one clock input
- Supports up to four SDRAM DIMMs
- Uses either I²C™-bus or SMBus serial interface with Read and Write capability for individual clock output control
- Output enable pin tristates all clock outputs to facilitate board testing
- Clock outputs skew-matched to less than 250ps
- Less than 5ns propagation delay
- Output impedance: 17Ω at 0.5V_{DD}
- Serial interface I/O meet I²C specifications; all other I/O are LVTTTL/LVCMOS-compatible
- Five different pin configurations available:
 - FS6050: 18 clock outputs in a 48-pin SSOP
 - FS6051: 10 clock outputs in a 28-pin SOIC, SSOP
 - FS6053: 13 clock outputs in a 28-pin SOIC
 - FS6054: 14 clock outputs in a 28-pin SOIC

Figure 1: Block Diagram (FS6050)



2.0 Description

The FS6050 family of CMOS clock fanout buffer ICs are designed for high-speed motherboard applications, such as Intel Pentium® II PC100-based systems with 100MHz SDRAM.

Up to eighteen buffered, non-inverting clock outputs are fanned-out from one clock input. Individual clocks are skew matched to less than 250ps at 100MHz. Multiple power and ground supplies reduce the effects of supply noise on device performance.

Under I²C-bus control, individual clock outputs may be turned on or off. An active-low output enable is available to force all the clock outputs to a tristate level for system testing.

Figure 2: Pin Configuration (FS6050)

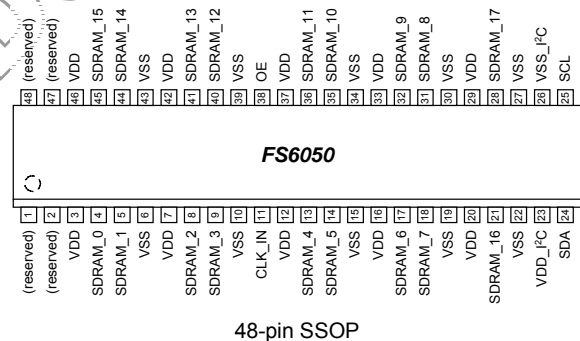
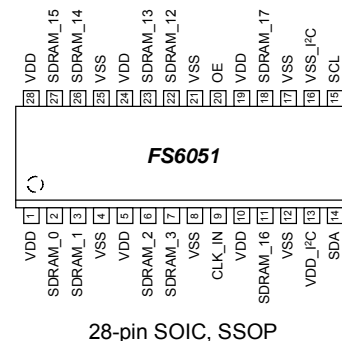


Figure 3: Pin Configuration (FS6051)



Additional pin configurations are noted on Page 2.

FS6050/FS6051/FS6053/FS6054

Low-Skew Clock Fanout Buffer ICs



Table 1: Pin Descriptions

Key: AI = Analog Input; AO = Analog Output; DI = Digital Input; DI^U = Input with Internal Pull-Up; DI^D = Input with Internal Pull-Down; DIO = Digital Input/Output; DI-3 = Three-Level Digital Input, DO = Digital Output; P = Power/Ground; # = Active Low pin

PIN (FS6050)	PIN (FS6051)	PIN (FS6053)	PIN (FS6054)	TYPE	NAME	DESCRIPTION
11	9	9	9	DI	CLK_IN	Clock input for SDRAM clock outputs
25	15	15	15	DI ^U	SCL	Serial clock input
24	14	14	14	DI ^U O	SDA	Serial data input/output
4	2	2	2	DO	SDRAM_0	SDRAM clock outputs (Byte 0)
5	3	3	3	DO	SDRAM_1	
8	6	6	6	DO	SDRAM_2	
9	7	7	7	DO	SDRAM_3	
13	-	-	-	DO	SDRAM_4	
14	-	-	-	DO	SDRAM_5	
17	-	10	10	DO	SDRAM_6	SDRAM clock outputs (Byte 1)
18	-	11	11	DO	SDRAM_7	
31	-	18	18	DO	SDRAM_8	
32	-	19	19	DO	SDRAM_9	
35	-	-	-	DO	SDRAM_10	
36	-	-	-	DO	SDRAM_11	
40	22	22	22	DO	SDRAM_12	SDRAM clock outputs (Byte 2)
41	23	23	23	DO	SDRAM_13	
44	26	26	26	DO	SDRAM_14	
45	27	27	27	DO	SDRAM_15	
21	11	12	12	DO	SDRAM_16	
28	18	-	17	DO	SDRAM_17	
38	20	-	20	DI ^U	OE	Output enable tristates all clock outputs when low
3, 7, 12, 16, 20, 29, 33, 37, 42, 46	1, 5, 10, 19, 24, 28	1, 5, 20, 24, 28	1, 5, 24, 28	P	VDD	3.3V ± 5% power supply for SDRAM clock buffers
23	13	13	13	P	VDD_I ² C	3.3V ± 5% power supply for serial communications
6, 10, 15, 19, 22, 27, 30, 34, 39, 43	4, 8, 12, 17, 21, 25	4, 8, 17, 21, 25	4, 8, 21, 25	P	VSS	Ground for SDRAM clock buffers
26	16	16	16	P	VSS_I ² C	Ground for serial communications
1, 2, 47, 48	-	-	-	-	(reserved)	Reserved

Figure 4: Pin Configuration (FS6053)

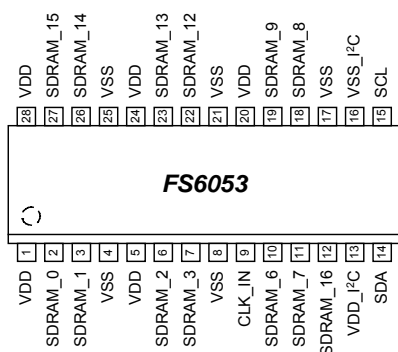
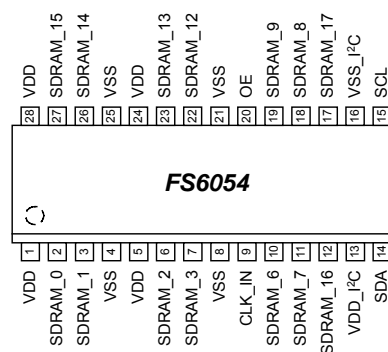


Figure 5: Pin Configuration (FS6054)



3.0 Programming Information

Table 2: Clock Enable

CONTROL INPUTS	CLOCK OUTPUTS (MHz)
OE	SDRAM_0:17
0	tristate
1	CLK_IN

3.1 Power-Up Initialization

All outputs are enabled and active upon power-up, and all output control register bits are initialized to one.

The outputs must be configured at power-up and are not expected to be configured during normal operation. Inactive outputs are held low and are disabled from switching.

3.1.1 Unused Outputs

Outputs that are not used in versions of this device with a reduced pinout are still operational internally. To reduce power dissipation and crosstalk effects from the unloaded outputs, it is recommended that these outputs be shut off via the Control Registers.

3.2 Register Programming

A logic-one written to a valid bit location turns on the assigned output clock. Likewise, a logic-zero written to a valid bit location turns off the assigned output clock.

Any unused or reserved register bits should be cleared to zero.

Serial bits are written to this device in the order shown in Table 3.

Table 3: Register Summary

SERIAL BIT	DATA BYTE	CLOCK OUTPUT
0	(MSB)	SDRAM_7
1	Byte 0 SDRAM Control Register 0	SDRAM_6
2		SDRAM_5
3		SDRAM_4
4		SDRAM_3
5		SDRAM_2
6		SDRAM_1
7	(LSB)	SDRAM_0
8	(MSB)	SDRAM_15
9	Byte 1 SDRAM Control Register 1	SDRAM_14
10		SDRAM_13
11		SDRAM_12
12		SDRAM_11
13		SDRAM_10
14		SDRAM_9
15	(LSB)	SDRAM_8
16	(MSB)	SDRAM_17
17	Byte 2 SDRAM Control Register 2	SDRAM_16
18		Reserved
19		Reserved
20		Reserved
21		Reserved
22		Reserved
23	(LSB)	Reserved

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Low-Skew Clock Fanout Buffer ICs



Table 4: Byte 0 - SDRAM Control Register 0

REGISTER BIT	CLOCK OUTPUT	DESCRIPTION	OUTPUT PIN (FS6050)	OUTPUT PIN (FS6051)	OUTPUT PIN (FS6053)	OUTPUT PIN (FS6054)
7	SDRAM_7	On (1) / Off (0)	Pin 18	-	Pin 11	Pin 11
6	SDRAM_6	On (1) / Off (0)	Pin 17	-	Pin 10	Pin 10
5	SDRAM_5	On (1) / Off (0)	Pin 14	-	-	-
4	SDRAM_4	On (1) / Off (0)	Pin 13	-	-	-
3	SDRAM_3	On (1) / Off (0)	Pin 9	Pin 7	Pin 7	Pin 7
2	SDRAM_2	On (1) / Off (0)	Pin 8	Pin 6	Pin 6	Pin 6
1	SDRAM_1	On (1) / Off (0)	Pin 5	Pin 3	Pin 3	Pin 3
0	SDRAM_0	On (1) / Off (0)	Pin 4	Pin 2	Pin 2	Pin 2

Table 5: Byte 1 - SDRAM Control Register 1

REGISTER BIT	CLOCK OUTPUT	DESCRIPTION	OUTPUT PIN (FS6050)	OUTPUT PIN (FS6051)	OUTPUT PIN (FS6053)	OUTPUT PIN (FS6054)
15	SDRAM_15	On (1) / Off (0)	Pin 45	Pin 27	Pin 27	Pin 27
14	SDRAM_14	On (1) / Off (0)	Pin 44	Pin 26	Pin 26	Pin 26
13	SDRAM_13	On (1) / Off (0)	Pin 41	Pin 23	Pin 23	Pin 23
12	SDRAM_12	On (1) / Off (0)	Pin 40	Pin 22	Pin 22	Pin 22
11	SDRAM_11	On (1) / Off (0)	Pin 36	-	-	-
10	SDRAM_10	On (1) / Off (0)	Pin 35	-	-	-
9	SDRAM_9	On (1) / Off (0)	Pin 32	-	Pin 19	Pin 19
8	SDRAM_8	On (1) / Off (0)	Pin 31	-	Pin 18	Pin 18

Table 6: Byte 2 - SDRAM Control Register 2

REGISTER BIT	CLOCK OUTPUT	DESCRIPTION	OUTPUT PIN (FS6050)	OUTPUT PIN (FS6051)	OUTPUT PIN (FS6053)	OUTPUT PIN (FS6054)
23	SDRAM_17	On (1) / Off (0)	Pin 28	Pin 18	-	Pin 17
22	SDRAM_16	On (1) / Off (0)	Pin 21	Pin 11	Pin 12	Pin 12
21		Reserved (set to 0)	-	-	-	-
20		Reserved (set to 0)	-	-	-	-
19		Reserved (set to 0)	-	-	-	-
18		Reserved (set to 0)	-	-	-	-
17		Reserved (set to 0)	-	-	-	-
16		Reserved (set to 0)	-	-	-	-

4.0 Dual Serial Interface Control

This integrated circuit is a read/write slave device that supports both the Inter IC Bus (I²C-bus) and the System Management Bus (SMBus) two-wire serial interface protocols. The unique device address that is written to the device determines whether the part expects to receive SMBus commands or I²C commands. Since SMBus is derived from the I²C-bus, the protocol for both bus types is very similar.

In general, the bus has to be controlled by a master device that generates the serial clock SCL, controls bus access, and generates the START and STOP conditions while the device works as a slave. Both master and slave can operate as a transmitter or receiver, but the master device determines which mode is activated. A device that sends data onto the bus is defined as the transmitter, and a device receiving data as the receiver.

Bus logic levels and timing parameters noted herein follow I²C-bus convention. Logic levels are based on a percentage of VDD. A logic-one corresponds to a nominal voltage of VDD, while a logic-zero corresponds to ground (VSS).

4.1 Bus Conditions

Data transfer on the bus can only be initiated when the bus is not busy. During the data transfer, the data line (SDA) must remain stable whenever the clock line (SCL) is high. Changes in the data line when the clock line is high is interpreted by the device as a START or STOP condition. Both I²C-bus and SMBus protocols define the following conditions on the bus. Refer to Figure 12: Bus Timing Data for more information.

4.1.1 Not Busy

Both the data (SDA) and clock (SCL) lines remain high to indicate the bus is not busy.

4.1.2 START Data Transfer

A high to low transition of the SDA line while the SCL input is high indicates a START condition. All commands to the device must be preceded by a START condition.

4.1.3 STOP Data Transfer

A low to high transition of the SDA line while SCL is held high indicates a STOP condition. All commands to the device must be followed by a STOP condition.

4.1.4 Data Valid

The state of the SDA line represents valid data if the SDA line is stable for the duration of the high period of the SCL line after a START condition occurs. The data on the SDA line must be changed only during the low period of the SCL signal. There is one clock pulse per data bit.

Each data transfer is initiated by a START condition and terminated with a STOP condition. The number of data bytes transferred between START and STOP conditions is determined by the master device, and can continue indefinitely. However, data that is overwritten to the device after the data registers are filled will overflow from the last register into the first register, then the second, and so on, in a first-in, first-overwritten fashion.

4.1.5 Acknowledge

When addressed, the receiving device is required to generate an Acknowledge after each byte is received. The master device must generate an extra clock pulse to coincide with the Acknowledge bit. The acknowledging device must pull the SDA line low during the high period of the master acknowledge clock pulse. Setup and hold times must be taken into account.

The master must signal an end of data to the slave by not generating an acknowledge bit on the last byte that has been read (clocked) out of the slave. In this case, the slave must leave the SDA line high to allow the master to generate a STOP condition.

4.2 Bus Operation and Commands

All programmable registers can be accessed via the bi-directional two wire digital interface. The device accepts the Random Register Read/Write and the Sequential Register Read/Write I²C commands. The device also supports the Block Read/Write SMBus commands.

4.2.1 I²C-bus and SMBus Device Addressing

After generating a START condition, the bus master broadcasts a seven-bit device address followed by a R/W bit. Note that every device on an I²C-bus or SMBus must have a unique address to avoid bus conflicts.

For an SMBus interface, the address of the device is:

A6	A5	A4	A3	A2	A1	A0
1	1	0	1	0	0	1

For an I²C-bus interface, the device can support two device addresses to permit multiple devices on one I²C-bus. The A2 address bit is ignored and can be set to either a one or a zero.

Therefore, for an I²C-bus interface the device address is:

A6	A5	A4	A3	A2	A1	A0
1	0	1	1	X	0	0

4.2.2 I²C-bus: Random Register Write Procedure



Random write operations, as shown in Figure 6, allow the master to directly write to any register. To initiate a write procedure, the R/W bit that is transmitted after the seven-bit I²C device address is a logic-low. This indicates to the addressed slave device that a register address will follow after the slave device acknowledges its device address. The register address is written into the slave's address pointer. Following an acknowledge by the slave, the master is allowed to write eight bits of data into the addressed register. A final acknowledge is returned by the device, and the master generates a STOP condition.

If either a STOP or a repeated START condition occurs during a Register Write, the data that has been transferred is ignored.

4.2.3 I²C-bus: Random Register Read Procedure

Random read operations allow the master to directly read from any register. To perform a read procedure, as shown in Figure 7, the R/W bit that is transmitted after the seven-bit I²C address is a logic-low, as in the Register Write procedure. This indicates to the addressed slave device that a register address will follow after the slave device acknowledges its device address. The register address is then written into the slave's address pointer.

Following an acknowledge by the slave, the master generates a repeated START condition. The repeated START terminates the write procedure, but not until after the slave's address pointer is set. The slave address is then resent, with the R/W bit set this time to a logic-high, indicating to the slave that data will be read. The slave will acknowledge the device address, and then transmits the eight-bit word. The master does not acknowledge the transfer but does generate a STOP condition.

4.2.4 I²C-bus: Sequential Register Write Procedure

Sequential write operations, as shown in Figure 8, allow the master to write to each register in order. The register pointer is automatically incremented after each write. This procedure is more efficient than the Random Register Write if several registers must be written.

To initiate a write procedure, the R/W bit that is transmitted after the seven-bit I²C device address is a logic-low. This indicates to the addressed slave device that a register address will follow after the slave device acknowledges its device address. The register address is written into the slave's address pointer. Following an acknowledge by the slave, the master is allowed to write data up to the last addressed register before the register address pointer overflows back to the beginning address. An acknowledge by the device between each byte of data must occur before the next data byte is sent.

Registers are updated every time the device sends an acknowledge to the host. The register update does not wait for the STOP condition to occur. Registers are therefore updated at different times during a Sequential Register Write.

4.2.5 I²C-bus: Sequential Register Read Procedure

Sequential read operations allow the master to read from each register in order. The register pointer is automatically incremented by one after each read. This procedure, as shown in Figure 9, is more efficient than the Random Register Read if several registers must be read from.

To perform a read procedure, the R/W bit that is transmitted after the seven-bit I²C address is a logic-low, as in the Register Write procedure. This indicates to the addressed slave device that a register address will follow after the slave device acknowledges its device address. The register address is then written into the slave's address pointer.

Following an acknowledge by the slave, the master generates a repeated START condition. The repeated START terminates the write procedure, but not until after the slave's address pointer is set. The slave address is then resent, with the R/W bit set this time to a logic-high, indicating to the slave that data will be read. The slave will acknowledge the device address, and then transmits all data starting with the initial addressed register. The register address pointer will overflow if the initial register address is larger than zero. After the last byte of data, the master does not acknowledge the transfer but does generate a STOP condition.

Figure 6: Random Register Write Procedure (I²C-bus)

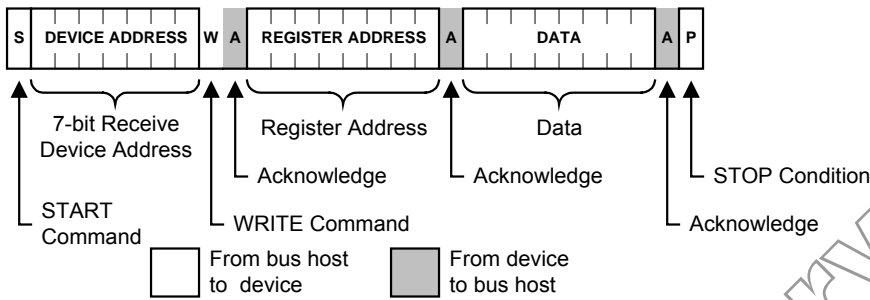


Figure 7: Random Register Read Procedure (I²C-bus)

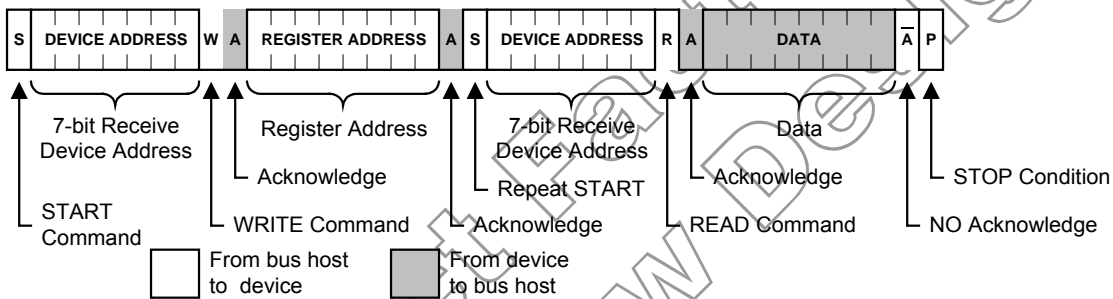


Figure 8: Sequential Register Write Procedure (I²C-bus)

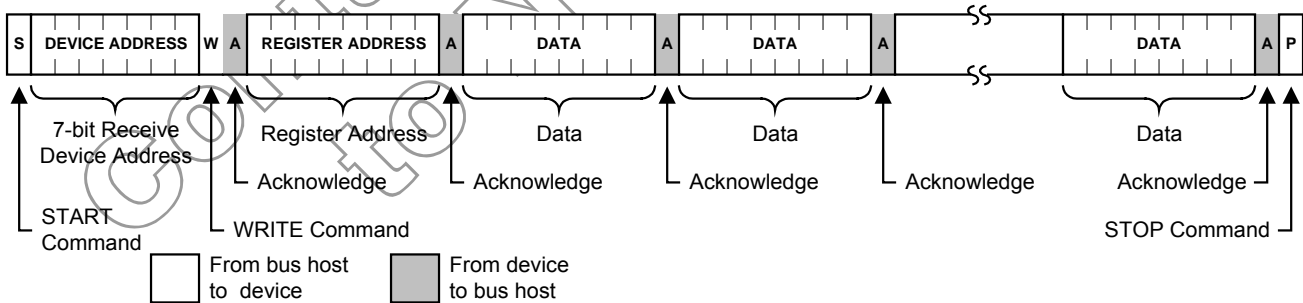
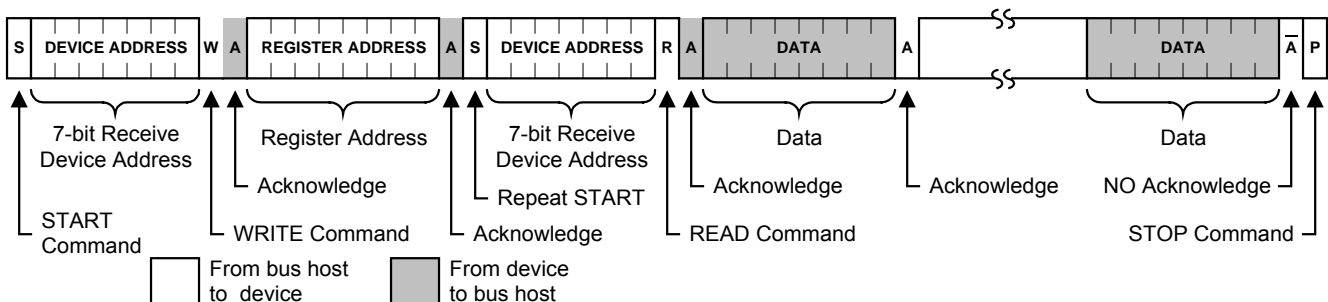


Figure 9: Sequential Register Read Procedure (I²C-bus)



4.2.6 SMBus: Block Write

SMBus

The Block Write command permits the master to write several bytes of data to sequential registers, starting by default at Register 0. The Block Write command, as noted in Figure 10, begins with the seven-bit SMBus device address followed by a logic-low R/W bit to begin a Write command. Following an acknowledge of the SMBus address and R/W bit by the slave device, a command code is written. *It is defined that all eight bits of the command code must be zero (0).*

After the command code of zero and an acknowledge, the host then issues a byte count that describes the number of data bytes to be written. According to SMBus convention, the byte count should be a value between 0 and 32; however this slave device ignores the byte count value.

Following an acknowledge of the byte count, data bytes may be written starting with Register 0 and incrementing sequentially. An acknowledge by the device between each byte of data must occur before the next data byte is sent.

registers, starting by default at Register 0. To perform a Block Read procedure the R/W bit that is transmitted after the seven-bit SMBus address is a logic-low, as in the Block Write procedure. The write bit resets the register address pointer to zero. Following an acknowledge of the SMBus address and R/W bit by the slave device, a command code is written. *It is defined that all eight bits of the command code must be zero (0).*

Following an acknowledge by the slave, the master generates a repeated START condition. The repeated START terminates the write procedure, but not until after the slave's address pointer is set. The slave SMBus address is then resent, with the R/W bit set this time to a logic-high, indicating to the slave that data will be read.

The slave will acknowledge the device address, and then will expect a byte count value (which will be ignored). Following the byte count value, the device will take command of the bus and will transmit all the data beginning with Register 0. After the last byte of data, the master does not acknowledge the transfer but does generate a STOP condition.

If the master does not want to receive all the data, the master can not acknowledge the last data byte and then can issue a STOP condition of the next clock.

4.2.7 SMBus: Block Read

The Block Read command, shown in Figure 11, permits the master to read several bytes of data from sequential

Figure 10: Block Write (SMBus)

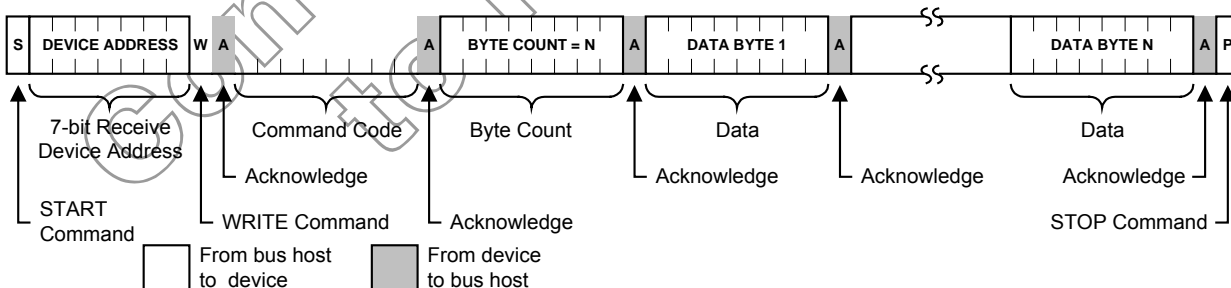
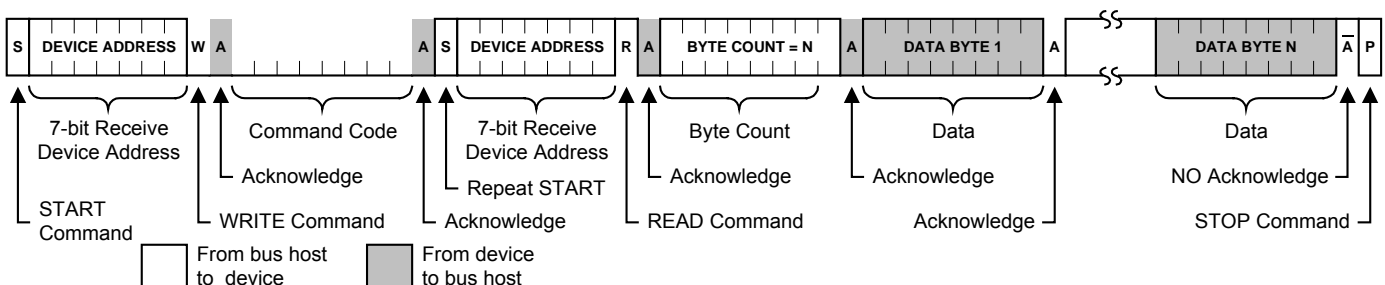


Figure 11: Block Read (SMBus)



5.0 Electrical Specifications

Table 7: Absolute Maximum Ratings

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These conditions represent a stress rating only, and functional operation of the device at these or any other conditions above the operational limits noted in this specification is not implied. Exposure to maximum rating conditions for extended conditions may affect device performance, functionality, and reliability.

PARAMETER	SYMBOL	MIN.	MAX.	UNITS
Supply Voltage, dc, Clock Buffers ($V_{SS} = \text{ground}$)	V_{DD}	$V_{SS}-0.5$	7	V
Supply Voltage, dc, Serial Communications	V_{DD_I2C}	$V_{SS}-0.5$	7	V
Input Voltage, dc	V_I	$V_{SS}-0.5$	$V_{DD}+0.5$	V
Output Voltage, dc	V_O	$V_{SS}-0.5$	$V_{DD}+0.5$	V
Input Clamp Current, dc ($V_I < 0$ or $V_I > V_{DD}$)	I_{IK}	-50	50	mA
Output Clamp Current, dc ($V_I < 0$ or $V_I > V_{DD}$)	I_{OK}	-50	50	mA
Storage Temperature Range (non-condensing)	T_S	-65	150	°C
Ambient Temperature Range, Under Bias	T_A	-55	125	°C
Junction Temperature	T_J		125	°C
Lead Temperature (soldering, 10s)			260	°C
Static Discharge Voltage Protection (MIL-STD 883E, Method 3015.7)			2	kV



CAUTION: ELECTROSTATIC SENSITIVE DEVICE

Permanent damage resulting in a loss of functionality or performance may occur if this device is subjected to a high-energy electrostatic discharge.

Table 8: Operating Conditions

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	MIN.	TYP.	MAX.	UNITS
Supply Voltage, Clock Buffers	V_{DD}	$3.3V \pm 5\%$	3.135	3.3	3.465	V
Supply Voltage, Serial Communications	V_{DD_I2C}	$3.3V \pm 5\%$	3.135	3.3	3.465	V
Ambient Operating Temperature Range	T_A		0		70	°C
Input Frequency	f_{CLK}		0		133	MHz
Output Load Capacitance	C_L				30	pF
Serial Data Transfer Rate		Standard mode	10	100	400	kb/s

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Table 9: DC Electrical Specifications

Unless otherwise stated, all power supplies = 3.3V \pm 5%, no load on any output, and ambient temperature range T_A = 0°C to 70°C. Parameters denoted with an asterisk (*) represent nominal characterization data and are not currently production tested to any specific limits. MIN and MAX characterization data are \pm 3 σ from typical. Negative currents indicate current flows out of the device.

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	MIN.	TYP.	MAX.	UNITS
Overall (FS6050)						
Supply Current, Dynamic, with Loaded Outputs	I_{DD}	$f_{CLK} = 100\text{MHz}$; $V_{DD} = 3.47\text{V}$		180	360	mA
Supply Current, Static	I_{DDL}	Outputs low; $V_{DD} = 3.47\text{V}$		0.75	3	mA
Serial Communication Inputs/Output (SDA, SCL)						
High-Level Input Voltage	V_{IH}	Outputs low	2.31		$V_{DD}+0.3$	V
Low-Level Input Voltage	V_{IL}	Outputs low	$V_{SS}-0.3$		0.9	V
Hysteresis Voltage *	V_{hys}	Outputs low	1.0			V
High-Level Input Current	I_{IH}		-1		1	μA
Low-Level Input Current (pull-up)	I_{IL}	Outputs low; $V_{IH} = 0.4\text{V}$, $V_{DD} = 3.47\text{V}$. Note: SDA requires an external pull-up to drive the data bus.	5	11	15	μA
Low-Level Output Sink Current (SDA)	I_{OL}	$V_{OL} = 0.4\text{V}$	10	25		mA
Output Enable Input (OE)						
High-Level Input Voltage	V_{IH}		2.0		$V_{DD}+0.3$	V
Low-Level Input Voltage	V_{IL}		$V_{SS}-0.3$		0.8	V
High-Level Input Current	I_{IH}		-1		1	μA
Low-Level Input Current (pull-up)	I_{IL}	$V_{TH} = 0.4\text{V}$; $V_{DD} = 3.47\text{V}$	10	22	30	μA
Clock Input (CLK_IN)						
High-Level Input Voltage	V_{IH}		2.0		$V_{DD}+0.3$	V
Low-Level Input Voltage	V_{IL}		$V_{SS}-0.3$		0.8	V
Input Leakage Current	I_I		-1		1	μA
Clock Outputs (SDRAM 0:17 3.3V Type 4 Clock Buffer)						
High-Level Output Source Current	$I_{OH\ min}$	$V_{DD} = 3.135\text{V}$, $V_O = 2.0\text{V}$	-54	-65		mA
	$I_{OH\ max}$	$V_{DD} = 3.465\text{V}$, $V_O = 3.135\text{V}$		-28	-46	
Low-Level Output Sink Current	$I_{OL\ min}$	$V_{DD} = 3.135\text{V}$, $V_O = 1.0\text{V}$	54	69		mA
	$I_{OL\ max}$	$V_{DD} = 3.465\text{V}$, $V_O = 0.4\text{V}$		33	53	
Output Impedance	Z_{OH}	$V_O = 0.5V_{DD}$; output driving high	10	17.9	24	Ω
	Z_{OL}	$V_O = 0.5V_{DD}$; output driving low	10	16.3	24	
Tristate Output Current	I_{OZ}		-5		5	μA
Short Circuit Source Current *	I_{OSH}	$V_O = 0\text{V}$; shorted for 30s, max.		-106		mA
Short Circuit Sink Current *	I_{OSL}	$V_O = 3.3\text{V}$; shorted for 30s, max.		107		mA

Table 10: AC Timing Specifications

Unless otherwise stated, all power supplies = 3.3V \pm 5%, no load on any output, and ambient temperature range T_A = 0°C to 70°C. Parameters denoted with an asterisk (*) represent nominal characterization data and are not currently production tested to any specific limits. MIN and MAX characterization data are \pm 3 σ from typical.

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	CLOCK (MHz)	MIN.	TYP.	MAX.	UNITS
Overall							
Clock Skew, Maximum; SDRAM_0 to any SDRAM pin *	t _{skw}	Measured on the rising edge at 1.5V; C _L = 20pF	66.67		182		ps
			100		228		
Propagation Delay, Average; CLK_IN to any SDRAM pin *	t _{PLH(min)}	Measured on the rising edge at 1.5V; C _L = 20pF	66.67		3.7		ns
			100		3.8		
	t _{PLH(max)}	Measured on the rising edge at 1.5V; C _L = 30pF	66.67		3.7		
			100		4.0		
	t _{PHL(min)}	Measured on the rising edge at 1.5V; C _L = 20pF	66.67		3.9		
			100		3.8		
t _{PHL(max)}	Measured on the rising edge at 1.5V; C _L = 30pF	66.67		4.2			
100		4.0					
Clock Outputs (SDRAM_0:17 3.3V Type 4 Clock Buffer)							
Rise Time *	t _{r(min)}	V _O = 0.4V to 2.4V; C _L = 20pF	66.67		1.0		ns
			100		0.9		
	t _{r(max)}	V _O = 0.4V to 2.4V; C _L = 30pF	66.67		1.2		
			100		1.0		
Fall Time *	t _{f(min)}	V _O = 2.4V to 0.4V; C _L = 20pF	66.67		1.0		ns
			100		0.7		
	t _{f(max)}	V _O = 2.4V to 0.4V; C _L = 30pF	66.67		1.1		
			100		0.8		
Clock High Time *	t _{KH(min)}	V _O = 2.4V; C _L = 20pF	66.67		6.5		ns
			100		3.8		
	t _{KH(max)}	V _O = 2.4V; C _L = 30pF	66.67		6.5		
			100		3.8		
Clock Low Time *	t _{KL(min)}	V _O = 0.4V; C _L = 20pF	66.67		6.5		ns
			100		4.6		
	t _{KL(max)}	V _O = 0.4V; C _L = 30pF	66.67		6.3		
			100		4.5		
Duty Cycle *		From rising edge to rising edge at 1.5V; C _L = 20pF	66.67		49		%
			100		45		
		From rising edge to rising edge at 1.5V; C _L = 30pF	66.67		50		
			100		46		
Tristate Enable Delay *	t _{PZL}	Output tristated to output active; C _L = 20pF			4.7		ns
	t _{PZH}				4.6		
Tristate Disable Delay *	t _{PLZ}	Output active to output tristated; C _L = 20pF			6.3		ns
	t _{PHZ}				7.9		

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Table 11: Serial Interface Timing Specifications

Unless otherwise stated, all power supplies = 3.3V \pm 5%, no load on any output, and ambient temperature range T_A = 0°C to 70°C. Parameters denoted with an asterisk (*) represent nominal characterization data and are not currently production tested to any specific limits. MIN and MAX characterization data are $\pm 3\sigma$ from typical.

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	MIN.	MAX.	UNITS
Clock frequency	f_{SCL}	SCL	10	400	kHz
Bus free time between STOP and START	t_{BUF}		4.7		μ s
Set up time, START (repeated)	$t_{su:STA}$		4.7		μ s
Hold time, START	$t_{hd:STA}$		4.0		μ s
Set up time, data input	$t_{su:DAT}$	SDA	250		ns
Hold time, data input	$t_{hd:DAT}$	SDA	300		ns
Output data valid from clock	t_{AA}	Minimum delay to bridge undefined region of the falling edge of SCL to avoid unintended START or STOP		3.5	μ s
Rise time, data and clock	t_r	SDA, SCL		1000	ns
Fall time, data and clock	t_f	SDA, SCL		300	ns
High time, clock	t_H	SCL	4.0		μ s
Low time, clock	t_L	SCL	4.7		μ s
Set up time, STOP	$t_{su:STO}$		4.0		μ s

Figure 12: Bus Timing Data

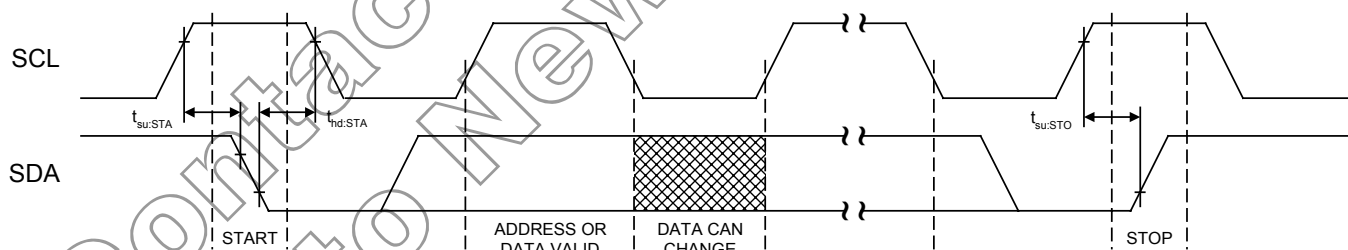


Figure 13: Data Transfer Sequence

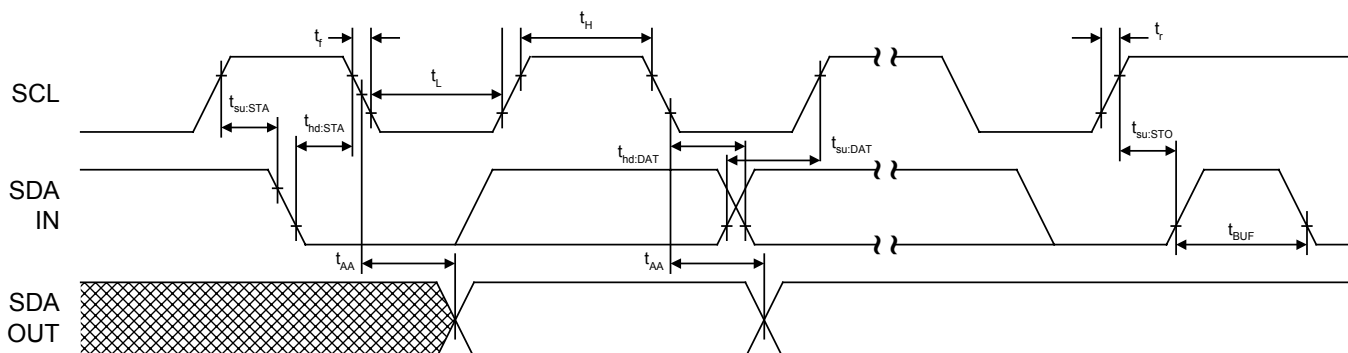


Figure 14: SDRAM_0:17 Clock Output (3.3V Type 4 Clock Buffer)

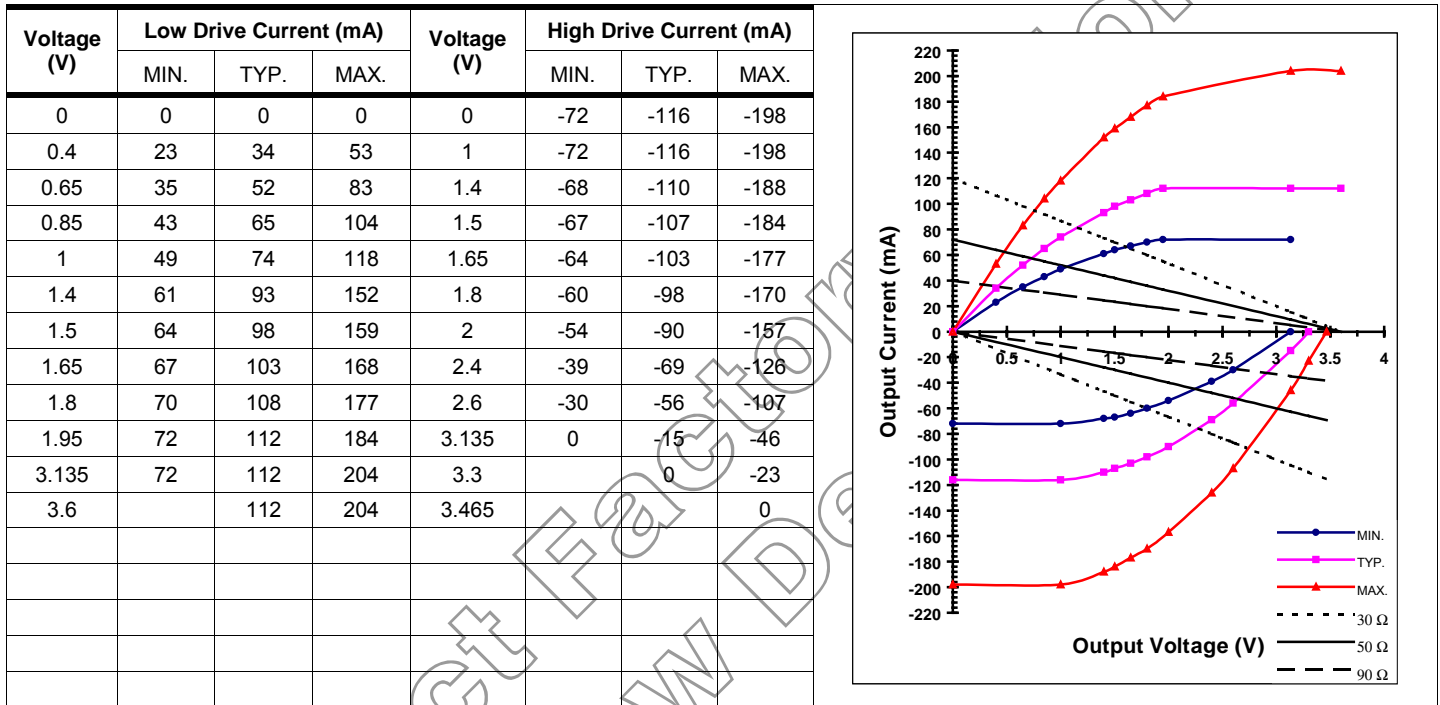


Figure 15: DC Measurement Points

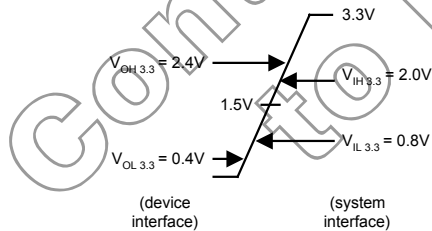


Figure 17: Timing Measurement Points

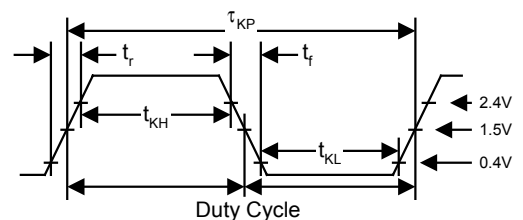
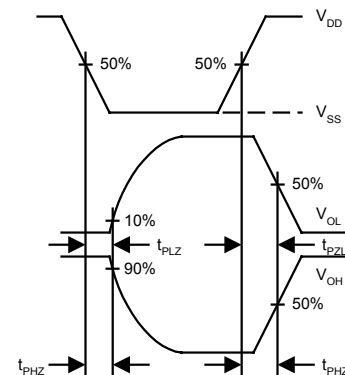
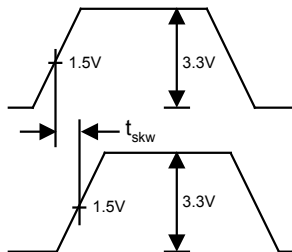


Figure 16: Clock Skew Measurement Point



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6.0 Package Information

Table 12: 48-pin SSOP (7.5mm/0.300") Package Dimensions

	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.095	0.110	2.41	2.79
A ₁	0.008	0.016	0.203	0.406
A ₂	0.088	0.092	2.24	2.34
B	0.008	0.0135	0.203	0.343
C	0.005	0.010	0.127	0.254
D	0.620	0.630	15.75	16.00
E	0.292	0.299	7.42	7.59
e	0.025 BSC		0.64 BSC	
H	0.400	0.410	10.16	10.41
h	0.010	0.016	0.254	0.410
L	0.024	0.040	0.610	1.02
θ	0°	8°	0°	8°

Table 13: 48-pin SSOP (7.5mm/0.300") Package Characteristics

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	TYP.	UNITS
Thermal Impedance, Junction to Free-Air	θ_{JA}	Air flow = 0 m/s	93	°C/W
Lead Inductance, Self	L ₁₁	Center lead	3.3	nH
Lead Inductance, Mutual	L ₁₂	Center lead to any adjacent lead	1.6	nH
Lead Capacitance, Bulk	C ₁₁	Center lead to V _{SS}	0.6	pF
Lead Capacitance, Mutual	C ₁₂	Center lead to any adjacent lead	0.2	pF

Table 14: 28-pin SOIC (7.5mm/0.300") Package Dimensions

	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.093	0.104	2.35	2.65
A ₁	0.004	0.012	0.10	0.30
A ₂	0.08	0.100	2.05	2.55
B	0.013	0.013	0.33	0.51
C	0.009	0.009	0.23	0.32
D	0.697	0.713	17.70	18.10
E	0.291	0.299	7.40	7.60
e	0.05 BSC		1.27 BSC	
H	0.393	0.419	10.00	10.65
h	0.010	0.030	0.25	0.75
L	0.016	0.05	0.40	1.27
Θ	0°	8°	0°	8°

The diagram illustrates the mechanical specifications of the 28-pin SOIC package. The top view shows the package body with the AMI logo and pin numbers 1 through 28. Key dimensions include overall length D, width B, and pin pitch e. The side view shows the package height H, standoff A, and lead height h. The lead detail view shows the lead thickness C, length L, and a 45-degree fillet. A note specifies that all radii should be between 0.005 and 0.01 inches. The base and seating planes are also indicated.

Table 15: 28-pin SOIC (7.5mm/0.300") Package Characteristics

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	TYP.	UNITS
Thermal Impedance, Junction to Free-Air	Θ_{JA}	Air flow = 0 m/s	80	°C/W
Lead Inductance, Self	L_{11}	Center lead	2.5	nH
Lead Inductance, Mutual	L_{12}	Center lead to any adjacent lead	0.85	nH
Lead Capacitance, Bulk	C_{11}	Center lead to V_{SS}	0.42	pF
Lead Capacitance, Mutual	C_{12}	Center lead to any adjacent lead	0.08	pF

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Table 16: 28-pin SSOP (5.3mm/0.209") Package Dimensions

	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
A	0.068	0.078	1.73	2.00
A ₁	0.002	0.008	0.05	0.21
A ₂	0.066	0.07	1.68	1.78
B	0.01	0.015	0.25	0.38
C	0.005	0.008	0.13	0.20
D	0.396	0.407	10.07	10.33
E	0.205	0.212	5.20	5.38
e	0.028 BSC		0.65 BSC	
H	0.301	0.311	7.65	7.90
L	0.022	0.037	0.55	0.95
Θ	0°	8°	0°	8°

Table 17: 28-pin SSOP (5.3mm/0.209") Package Characteristics

PARAMETER	SYMBOL	CONDITIONS/DESCRIPTION	TYP.	UNITS
Thermal Impedance, Junction to Free-Air	Θ_{JA}	Air flow = 0 m/s	97	°C/W
Lead Inductance, Self	L_{11}	Center lead	2.24	nH
Lead Inductance, Mutual	L_{12}	Center lead to any adjacent lead	0.95	nH
Lead Capacitance, Bulk	C_{11}	Center lead to V_{SS}	0.25	pF
Lead Capacitance, Mutual	C_{12}	Center lead to any adjacent lead	0.07	pF

7.0 Ordering Information

DEVICE NUMBER	ORDERING CODE	PACKAGE TYPE	OPERATING TEMPERATURE RANGE	SHIPPING CONFIGURATION
FS6050	11257-801	48-pin (7.5mm/0.300") SSOP	0°C to 70°C (Commercial)	Tape and Reel
	11257-811	48-pin (7.5mm/0.300") SSOP	0°C to 70°C (Commercial)	Tube
FS6051	11257-802	28-pin (7.5mm/0.300") SOIC	0°C to 70°C (Commercial)	Tape and Reel
	11257-812	28-pin (7.5mm/0.209") SOIC	0°C to 70°C (Commercial)	Tube
	11257-806	28-pin (5.3mm/0.209") SSOP	0°C to 70°C (Commercial)	Tape and Reel
	11257-816	28-pin (5.3mm/0.209") SSOP	0°C to 70°C (Commercial)	Tube
FS6053	11257-803	28-pin (7.5mm/0.300") SOIC	0°C to 70°C (Commercial)	Tape and Reel
	11257-813	28-pin (7.5mm/0.300") SOIC	0°C to 70°C (Commercial)	Tube
FS6054	11257-804	28-pin (7.5mm/0.300") SOIC	0°C to 70°C (Commercial)	Tape and Reel
	11257-814	28-pin (7.5mm/0.300") SOIC	0°C to 70°C (Commercial)	Tube



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8.0 Application Information

8.1 Reduction of EMI

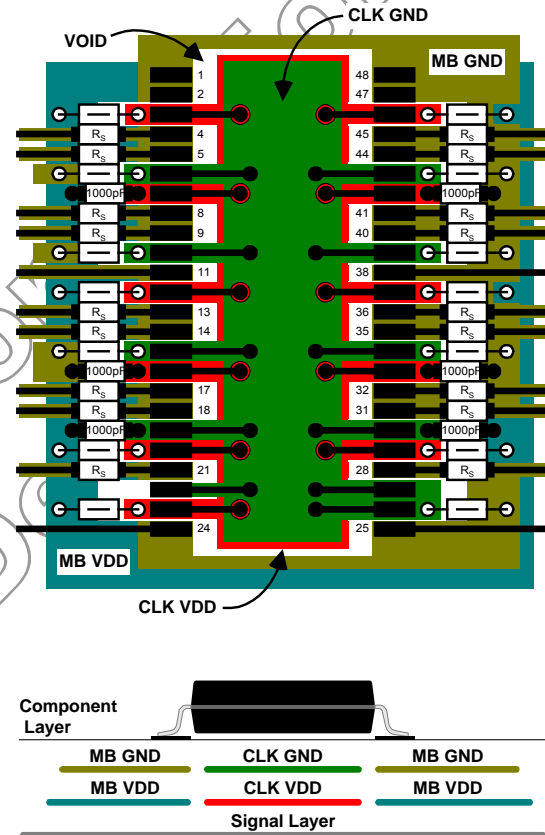
The primary concern when designing the board layout for this device is the reduction of electromagnetic interference (EMI) generated by the 18 copies of the 100MHz SDRAM clock. It is assumed the reader is familiar with basic transmission line theory.

8.1.1 Layout Guidelines

To obtain the best performance, noise should be minimized on the power and ground supplies to the IC. Observe good high-speed board design practices, such as:

- Use multi-layer circuit boards with dedicated low impedance power and ground planes for the device (denoted as CLK VDD and CLK GND in Figure 18). The device power and ground planes should be completely isolated from the motherboard power and ground planes by a void in the power planes.
- Several low-pass filters using low impedance ferrite beads (5Ω at 100MHz) are recommended to decouple the device power and ground planes from the motherboard power and ground planes (MB VDD and MB GND). The beads should span the gap between the power and ground planes. Seven beads for power and seven beads for ground are suggested (14 total) so that the clock rise times (1V/ns) can be maintained.
- Place 1000pF bypass capacitors as close as possible to the power pins of the IC. Use RF-quality low-inductance multi-layer ceramic chip capacitors. Six capacitors is optimal, one on each power/ground grouping as shown in Figure 18.
- Load similar clock outputs equally, and keep output loading as light as possible to help reduce clock skew and power dissipation.
- Use equal-length clock traces that are as short as possible. Rounded trace corners help reduce reflections and ringing in the clock signal.
- The clock traces must never cross the void area between power/ground planes. Each trace must have a complete plane (either VDD or GND) under the complete length of the trace.

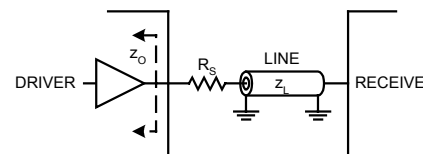
Figure 18: Board Layout



8.1.2 Output Driver Termination

A signal reflection will occur at any point on a PC-board trace where impedance mismatches exist. Reflections cause several undesirable effects in high-speed applications, such as an increase in clock jitter and a rise in electromagnetic emissions from the board. Using a properly designed series termination on each high-speed line can alleviate these problems by eliminating signal reflections.

Figure 19: Series Termination



Series termination adds no dc loading to the driver, and requires less power than other resistive termination methods. Further, no extra impedance exists from the signal line to a reference voltage, such as ground.

As shown in Figure 19, the sum of the driver's output impedance (z_o) and the series termination resistance (R_s) must equal the line impedance (z_L). That is,

$$R_s = z_L - z_o.$$

Note that when the source impedance ($z_o + R_s$) is matched to the line impedance, then by voltage division the incident wave amplitude is one-half of the full signal amplitude.

$$V_i = V \frac{(z_o + R_s)}{(z_o + R_s) + z_L} = \frac{V}{2}$$

The full signal amplitude may take up to twice as long as the propagation delay of the line to develop, reducing noise immunity during the half-amplitude period. Note also that the voltage at the receive end must add up to a signal amplitude that meets the receiver switching thresholds. The slew rate of the signal is also reduced due to the additional RC delay of the load capacitance and the line impedance. Also note that the output driver impedance will vary slightly with the output logic state (high or low).

8.2 Dynamic Power Dissipation

High-speed clock drivers require careful attention to power dissipation. Transient power (P_T) consumption can be derived from

$$P_T = V_{DD}^2 \times C_{load} \times f_{CLK} \times N_{SW}$$

where C_{load} is the load capacitance, V_{DD} is the supply voltage, f_{CLK} is the clock frequency, and N_{SW} is the number of switching outputs.

The internal heat (junction temperature, T_J) generated by the power dissipation can be calculated from

$$T_J = \Theta_{JA} \times P_T + T_A$$

where Θ_{JA} is the package thermal resistance, T_A is the ambient temperature, and P_T is derived above.

8.3 Serial Communications

Connection of devices to a standard-mode implementation of either the I²C-bus or the SMBus is similar to that shown in Figure 20. Selection of the pull-up resistors (R_p) and the optional series resistors (R_s) on the SDA and SCL lines depends on the supply voltage, the bus ca-

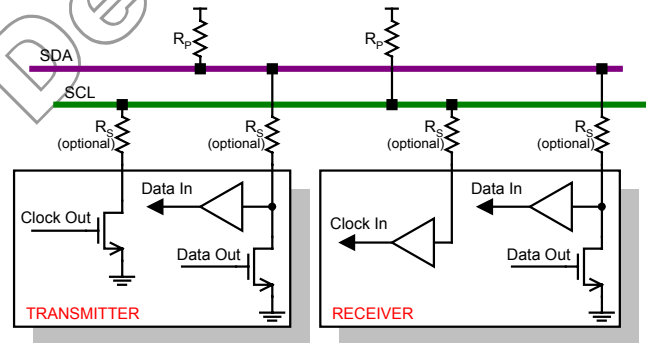
pacitance, and the number of connected devices with their associated input currents.

Control of the clock and data lines is done through open drain/collector current-sink outputs, and thus requires external pull-up resistors on both lines. A guideline is

$$R_p \leq \frac{t_r}{2 \times C_{bus}},$$

where t_r is the maximum rise time (minus some margin) and C_{bus} is the total bus capacitance. Assuming an I²C device on each DIMM, an I²C controller, the clock buffer, and two other bus devices results in values in the 5k Ω to 7k Ω range. Use of a series resistor to provide protection against high voltage spikes on the bus will alter the values for R_p .

Figure 20: Connections to the Serial Bus



8.3.1 For More Information

More detailed information on serial bus design can be obtained from SMBus and I²C Bus Design, available from the Intel Corporation at <http://www.intel.com>.

Information on the I²C-bus can be found in the document The I²C-bus And How To Use It (Including Specifications), available from Philips Semiconductors at <http://www-us2.semiconductors.philips.com>.

Additional information on the System Management Bus can be found in the System Management Bus Specification, available from the Smart Battery System Implementers' Forum at <http://www.sbs-forum.org>.